Memory Microcircuit - Page 1 of 1



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## **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

# Storage Tempurature Range:

-65.0/+150.0 degrees celsius

## End Application:

Display conso e/i fscm 49956

#### Features Provided:

Bipolar and electrically alterable and low power and programmed and high reliability

## **Inclosure Material:**

Ceramic

## Inclosure Configuration:

Dual-in-line

## **Output Logic Form:**

Transistor-transistor logic

## Case Outline Source And Designator:

D-2 mil-m-38510

## **Current Rating Per Characteristic:**

100.00 milliamperes average forward current averaged over a full 60-hz cycle not applicable

## **Terminal Surface Treatment:**

Solder

## **Product Name:**

1024-bit bipola (256x4) electrically programmable read only memory

# Voltage Rating And Type Per Characteristic:

-0.5 volts applied and 7.0 volts applied

## Memory Device Type:

Eeprom

## Hybrid Technology Type:

Monolithic

## **Terminal Type And Quantity:**

16 printed circuit

## **Purchase Description Identification:**

4995-69-797-3811

## Shelf Life:

N/a

## Unit Of Measure:

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## Demilitarization:

Yes - demil/mli

Fiig:

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